NSVMMUN2212LT1G Information

For Reference Only

Part Number	NSVMMUN2212LT1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single, Pre-Biased
Description	TRANS PREBIAS NPN 0.246W SOT23
Package	TO-236-3, SC-59, SOT-23-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

NSVMMUN2212LT1G Specifications

Manufacturer Part Number	NSVMMUN2212LT1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	22k
Resistor - Emitter Base (R2) (Ohms)	22k
DC Current Gain (hFE) (Min) @ Ic, Vce	60 @ 5mA, 10V
Vce Saturation (Max) @ Ib, Ic	250mV @ 300μA, 10mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	-
Power - Max	246mW
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	SOT-23-3 (TO-236)
	Report errors?

NSVMMUN2212LT1G Guarantees

Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NSVMMUN2212LT1G Payment Methods

NSVMMUN2212LT1G Shipping Methods

If you have any question about NSVMMUN2212LT1G, please do not hesitate to contact us!

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